

3-Phase Diode Bridge

DF30AA120/160

UL; E76102

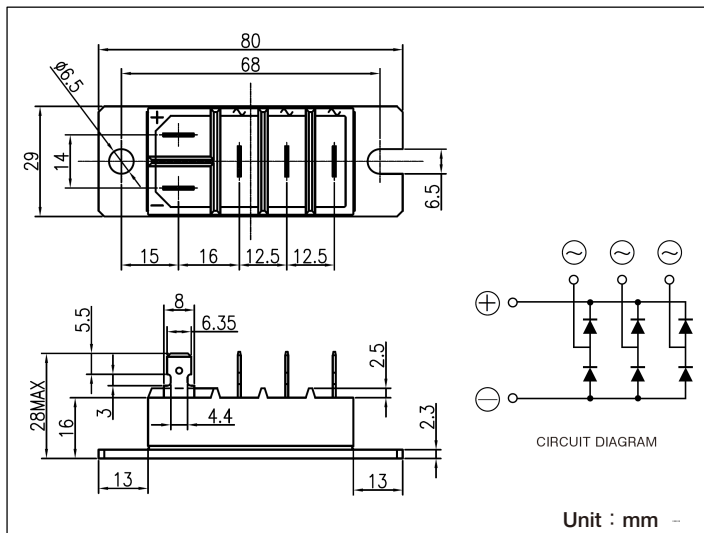
《Features》

Power Diode Module DF30AA is designed for three phase full wave rectification, which has six diodes connected in a three phase bridge configuration. The mounting base of the module is electrically isolated from semiconductor elements for simple heatsink construction output. DC current is 30Amp (Tc=117°C). Repetitive peak reverse voltage is up to 1,600V.

- TjMax=150°C
- Isolated Mounting Base
- High reliability by unique glass passivation
- Easy Assemble by the #250 terminal Tab

《Applications》

- AC, DC Motor Drive / AVR / Switching — for three phase rectification



■ Maximum Ratings (Tj=25°C unless otherwise specified)

Item	Symbol	Unit	DF30AA120	DF30AA160
Repetitive Peak Reverse Voltage	V_{RRM}	V	1200	1600
Non-Repetitive Peak Reverse Voltage	V_{RSM}	V	1300	1700

Item	Symbol	Unit	Ratings	Conditions
Output Current (DC)	I_D	A	30	$T_c=117^\circ\text{C}$
Surge Forward Current	I_{FSM}	A	270/300	1/2cycle, 50/60Hz, Peak value, non-repetitive
Operating Junction Temperature	T_j	°C	-40 to +150	
Storage Temperature	T_{stg}	°C	-40 to +125	
Isolation Breakdown Voltage (RMS)		V	2500	AC 1minute
Mounting torque	Mounting M6	N·m (kgf·cm)	4.7(48)	Recommended Value 2.5 to 3.9 (25 to 40)
	Mounting M5		2.7(28)	Recommended Value 1.5 to 2.5 (15 to 25)
Mass		g	90	Typical

■ Electrical Characteristics (Tj=25°C unless otherwise specified)

Item	Symbol	Unit	Ratings			Conditions
			Min.	Typ.	Max.	
Repetitive Peak Reverse Current	I_{RRM}	mA			3.0	$T_j=150^\circ\text{C}$ at V_{RRM}
Forward Voltage Drop	V_{FM}	V			1.30	Forward current 30A
Threshold Voltage	$V_{(TO)}$	V			0.85	$T_j=150^\circ\text{C}$
Dynamic Resistance	r_t	mΩ			10.3	$T_j=150^\circ\text{C}$
Thermal Resistance	$R_{th(j-c)}$	°C/W			0.42	Junction to case per module
Interface Thermal Resistance	$R_{th(c-f)}$	°C/W			0.1	Case to Heat Sink Thermal conductivity (Silicon grease) $\approx 7 \times 10^{-3} [\text{W}/\text{cm} \cdot ^\circ\text{C}]$

